MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data sheet



FEATURE

- Switching and amplification in high voltage Applications such as telephony
- Low current(max. 500mA)
- High voltage(max.160v)





- 1. BASE
- 2. COLLECTOR
- 3. EMITTER

MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

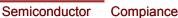
Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-160	٧
V _{CEO}	Collector-Emitter Voltage	-150	>
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current -Continuous	-0.5	Α
Pc	Collector Power Dissipation	0.5	W
R _{θJA}	Thermal Resistance From Junction To Ambient	250	°C/W
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55~150	$^{\circ}$

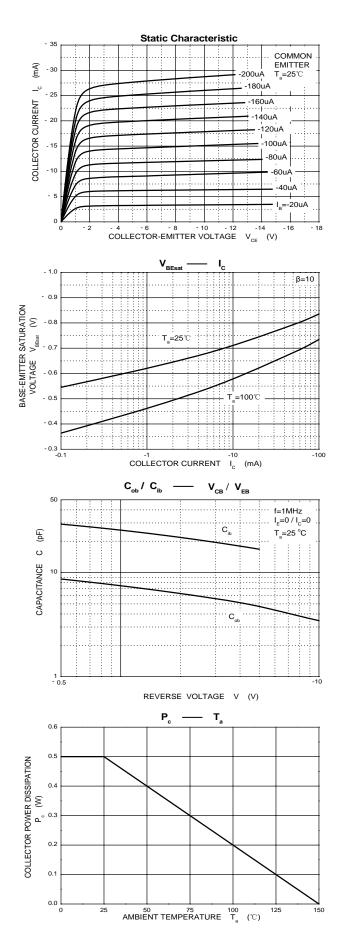
ELECTRICAL CHARACTERISTICS(Ta=25°C unless otherwise specified)

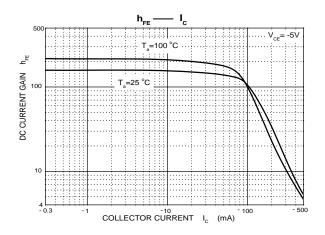
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = -100μA, I _E =0	-160			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	$I_{C} = -1 \text{mA}, I_{B} = 0$	-150			V
Emitter-base breakdown voltage	V _{(BR)EBO}	$I_E = -10\mu A, I_C = 0$	-5			V
Collector cut-off current	I _{CBO}	V _{CB} = -120 V, I _E =0			-50	nA
Emitter cut-off current	I _{EBO}	V _{EB} = -3V, I _C =0			-50	nA
	h _{FE(1)}	V_{CE} = -5V, I_{C} =-1 mA	50			
DC current gain	h _{FE(2)}	V_{CE} = -5V, I_{C} = -10 mA	100		300	
	h _{FE(3)}	V _{CE} = -5V, I _C =-50 mA	50			
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = -10 mA, I _B = -1 mA			-0.2	V
Collector-enlitter Saturation Voltage	V _{CE(sat)}	I_C = -50 mA, I_B = -5 mA			-0.5	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C = -10 mA, I _B = -1 mA			-1	V
Base-enlitter saturation voltage	V _{BE(sat)}	I_C = -50 mA, I_B = -5 mA			-1	V
Transition frequency	f _T	V_{CE} = -10V, I_{C} = -10mA, f = 100MHz	100		300	MHz
Output Capacitance	C _{ob}	V _{CB} =-10V, I _E = 0,f=1MHz			6	pF
Noise Figure	NF	V_{CE} = -5.0V, I_{C} = -200 μ A, R_{S} = 10 Ω , f =10Hz to15.7kHz			8	dB

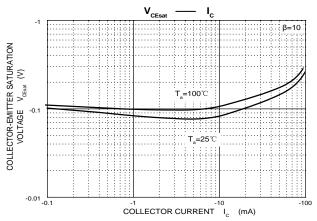


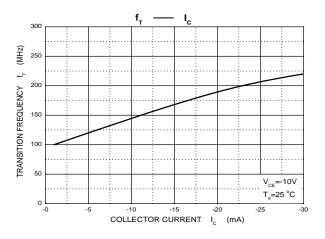






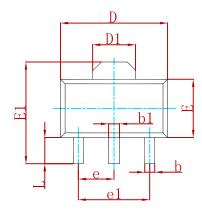


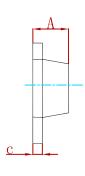






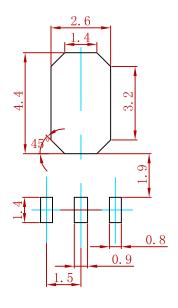
PACKAGE MECHANICAL DATA





Symbol	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min	Max	Min	Max
Α	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
С	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550	REF.	0.061	REF.
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
е	1.500	TYP.	0.060	TYP.
e1	3.000	TYP.	0.118	TYP.
L	0.900	1.200	0.035	0.047

Suggested Pad Layout



- 1. Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
CXT5401	SOT-89	1000



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